VS-16CTQ060-M3, VS-16CTQ080-M3, VS-16CTQ100-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 8 A



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PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 8 A					
V _R	60 V, 80 V, 100 V					
V _F at I _F	0.58 V					
I _{RM} max.	7 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	7.5 mJ					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation



HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	IBOL CHARACTERISTICS VALUES U						
I _{F(AV)}	Rectangular waveform	16	А				
V _{RRM}		60 to 100	V				
I _{FSM}	t _p = 5 μs sine	850	А				
V _F	8 A _{pk} , T _J = 125 °C (per leg)	0.58	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-16CTQ060-M3	VS-16CTQ080-M3	VS-16CTQ100-M3	UNITS		
Maximum DC reverse voltage	V _R	60	80	100	М		
Maximum working peak reverse voltage	V _{RWM}	00	00	100	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward per le	о	$I_{F(AV)}$ 50 % duty cycle at T _C = 148 °C, rectangular waveform		8	А			
current, see fig. 5 per devie				16	A			
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	850	А			
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	275	~			
Non-repetitive avalanche energy per le	g E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 0.50 \text{ A}, L = 60 \text{ mH}$		7.50	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	А			

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 1
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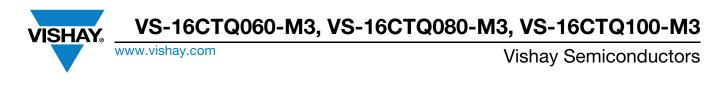
ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		8 A	T _{.1} = 25 °C	0.72			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	16 A	1j=23 0	0.88	V		
See fig. 1	VFM (*)	8 A	T _{.1} = 125 °C	0.58			
		16 A	1j = 125 C	0.69			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = rated $V_{\rm B}$	0.55	mA		
See fig. 2	IRM (")	T _J = 125 °C	$v_{\rm R} = rateu v_{\rm R}$	7.0			
Threshold voltage	V _{F(TO)}	T _{.1} = T _{.1} maximum		0.415	V		
Forward slope resistance	r _t	ij = ij maximum		11.07	mΩ		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	500	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

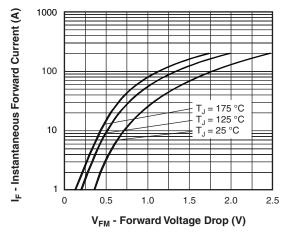
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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to 175	°C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	3.25	°C/W				
Maximum thermal resistance junction to case per package	R _{thJC}		1.63	0/10				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting to your			6 (5)	kgf∙cm				
Mounting torque maximum			12 (10)	(lbf ⋅ in)				
			16CT	Q060				
Marking device		Case style 3L TO-220AB	16CTQ080					
			16CTQ100					



100



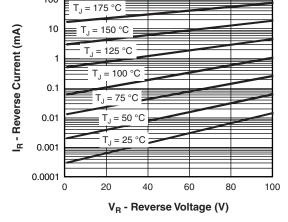


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

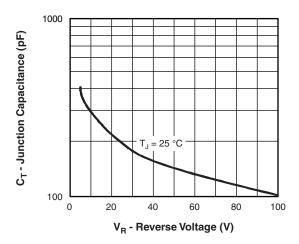


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

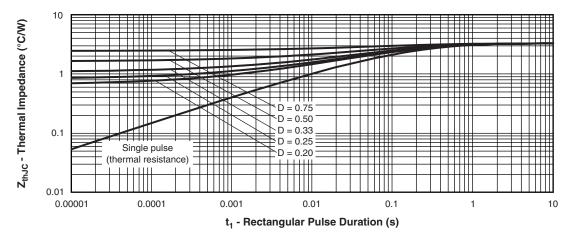
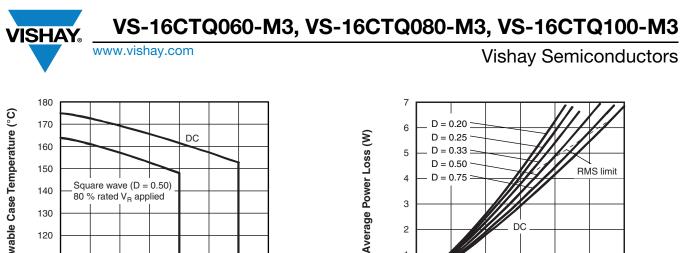


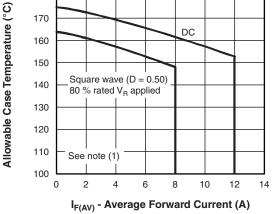
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

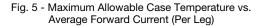
 Revision: 20-Nov-17
 3
 Document Number: 96272

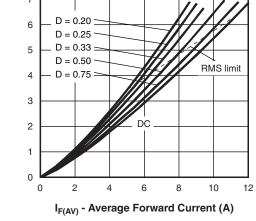
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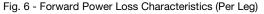
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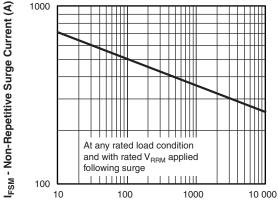












tp - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

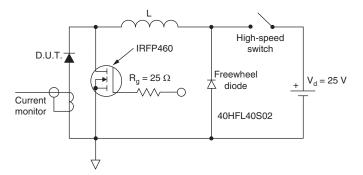


Fig. 8 - Unclamped Inductive Test Circuit

Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; (1) Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6);

 Pd_{REV} = inverse power loss = $V_{B1} \times I_B (1 - D)$; I_B at V_{B1} = 80 % rated V_B applied

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4

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ORDERING INFORMATION TABLE

VISHAY

Device code	VS-	16	С	т	Q	100	-M3
	1	2	3	4	5	6	7
	1 - 2 - 3 -	Cur Circ	nay Serr rent rati cuit confi commo	ng (16 = iguratior	: 16 A) 1	oduct	
	4		kage TO-220)			
	5 - 6 -		ottky "Q age rati				060 = 60 V 080 = 80 V
	7		vironmer	0			100 = 100 V

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-16CTQ060-M3	50	1000	Antistatic plastic tube				
VS-16CTQ080-M3	50	1000	Antistatic plastic tube				
VS-16CTQ100-M3	50	1000	Antistatic plastic tube				

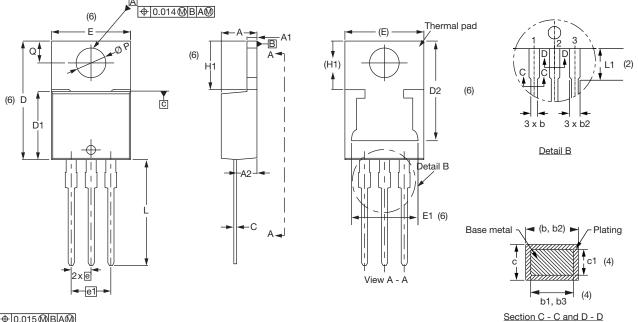
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96154					
Part marking information	www.vishay.com/doc?95028				
SPICE model	www.vishay.com/doc?95279				



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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015 BA





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
с	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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1

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